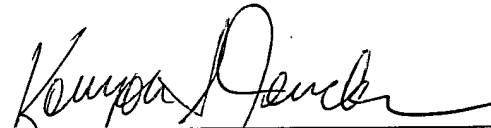


REMARKS


Attached is a marked-up version of the changes being made by the current amendment. Please apply any applicable charges or credits to Deposit Account No. 06-1050.

Respectfully submitted,

Date: December 26, 2002

  
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Version with markings to show changes made

In the claims:

Claims 17-20 have been amended as follows:

-- 17. (Amended) A method according to any one of claims 1, 2, 9 and 10, [to 16,] wherein said semiconductor layer comprises amorphous silicon.

18. (Amended) A method according to any one of claims 1, 2, 9 and 10, [to 16,] wherein said semiconductor layer comprises silicon and germanium.

19. (Amended) A method according to any one of claims 1, 2, 9 and 10, [to 16,] wherein the crystallized semiconductor layer contains carbon at a concentration not higher than  $5 \times 10^{18}$  atoms/cm<sup>3</sup>.

20. (Amended) A method according to any one of claims 1, 2, 9 and 10, [to 16,] wherein the crystallized semiconductor layer contains oxygen at a concentration not higher than  $5 \times 10^{19}$  atoms/cm<sup>3</sup>.

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